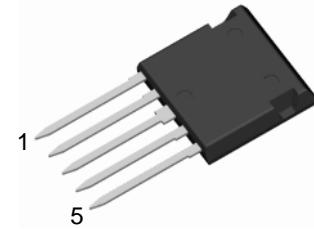
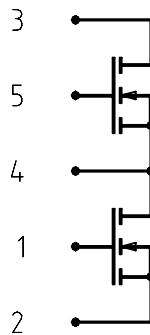


HiPerFET™
Power Mosfet
-Phaseleg Topology-
in ISOPLUS i4-PAC™

FMM 75-01F

I_{D25} = 75 A
V_{DSS} = 100 V
R_{DSon} = 25 mΩ

**MOSFETs**

| Symbol | Conditions | Maximum Ratings | | |
|------------------|--|-----------------|------|----|
| V _{DSS} | T _{VJ} = 25°C to 150°C | 100 | | V |
| V _{GS} | | ±20 | | V |
| I _{D25} | T _C = 25°C | 75 | | A |
| I _{D90} | T _C = 90°C | 50 | | A |
| I _{F25} | (diode) T _C = 25°C | 100 | | A |
| I _{F90} | (diode) T _C = 90°C | 60 | | A |
| dv/dt | V _{DS} < V _{DSS} ; I _F ≤ 300A; dv/dt ≤ 100A/μs; R _G = 2 Ω T _{VJ} = 150°C | 5 | V/ns | |
| E _{AR} | T _C = 25°C | 30 | | mJ |

| Symbol | Conditions | Characteristic Values | | |
|---|--|--|----------------------|-------|
| | | (T _{VJ} = 25°C, unless otherwise specified) | min. | typ. |
| R _{DSon} | V _{GS} = 10 V; I _D = I _{D90} | | | 25 mΩ |
| V _{GSth} | V _{DS} = 20 V; I _D = 4 mA; | 2 | | 4 V |
| I _{DSS} | V _{DS} = V _{DSS} ; V _{GS} = 0 V; T _{VJ} = 25°C T _{VJ} = 125°C | 0.25 | 0.3 mA | mA |
| I _{GSS} | V _{GS} = ±20 V; V _{DS} = 0 V | | 200 | nA |
| Q _g Q _{gs} Q _{gd} | { V _{GS} = 10 V; V _{DS} = 0.5 • V _{DSS} ; I _D = I _{D90} | 180 35 85 | nC nC nC | |
| t _{d(on)} t _r t _{d(off)} t _f | { V _{GS} = 10 V; V _{DS} = 0.5 • V _{DSS} ; I _D = I _{D90} ; R _G = 2 Ω | 20 60 80 60 | ns ns ns ns | |
| V _F | (diode) I _F = 75 A; V _{GS} = 0 V | 1.2 | 1.5 | V |
| t _{rr} | (diode) I _F = 37.5 A; -di/dt = 100 A/μs; V _{DS} = 25 V | 300 | | ns |
| R _{thJC} | | | 0.5 | K/W |

Features

- HiPerFET™ technology
 - low R_{DSon}
 - low gate charge for high frequency operation
 - unclamped inductive switching (UIS) capability
 - dv/dt ruggedness
 - fast intrinsic reverse diode
- ISOPLUS i4-PAC™ package
 - isolated back surface
 - enlarged creepage towards heatsink
 - application friendly pinout
 - low inductive current path
 - high reliability
 - industry standard outline

Applications

- drives and power supplies
- battery or fuel cell powered
- automotive, industrial vehicle etc.
- secondary side of mains power supplies

Component

| Symbol | Conditions | Maximum Ratings | | |
|------------|--|-----------------|----|----|
| T_{VJ} | | -55...+150 | | °C |
| T_{stg} | | -55...+125 | | °C |
| V_{ISOL} | $I_{ISOL} \leq 1 \text{ mA}; 50/60 \text{ Hz}$ | 2500 | V- | |
| F_c | mounting force with clip | 20...120 | N | |

| Symbol | Conditions | Characteristic Values | | |
|---------------|------------------------|-----------------------|------|------|
| | | min. | typ. | max. |
| d_s, d_A | pin - pin | 1.7 | | mm |
| d_s, d_A | pin - backside metal | 5.5 | | mm |
| R_{thCH} | with heatsink compound | 0.15 | | K/W |
| Weight | | 9 | | g |

Dimensions in mm (1 mm = 0.0394")